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correlations in Se-rich glassy arsenic selenides

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Abstract

The X-ray powder diffraction (XRPD) patterns related to the first sharp diffraction peak (FSDP) are registered for Se-rich $\text{As}_x\text{Se}_{100-x}$ glasses ($5 \leq x \leq 40$), subjected to high-energy mechanical milling in a dry mode with 500 min^{-1} rotational speed. The results are treated in terms of structural model assuming broad diffraction halos in the XRPD patterns appeared due to remnants of *inter-planar* “quasi-crystalline” correlations, disturbed by overlapping with diffuse halos originated from strongest *inter-atomic* correlations, in part, the nearest-neighbor correlations between cation-like atoms. Milling does not influence the FSDP in a vicinity of glassy Se ($x < 20$), while causes increase in the FSDP width ΔQ (the reduced correlation length L) in the glasses with $20 \leq x < 40$, these changes being ascribed to disturbed inter-planar arrangement in covalent-bonded network due to structural defects generated under attrition ball milling. Assuming contribution of the Ehrenfest diffraction from coordination spheres in the detected XRPD patterns, the latter is ascribed to broadening in the distribution of characteristic FSDP-related inter-atomic distances, thus testifying in a favor of more defective structure of milled glass.

Key words: glass; arsenic selenide; mechanical milling; X-ray powder diffraction; first sharp diffraction peak.

The high-energy mechanical milling (MM) is known to be an effective technological tool allowing substances preparation in a variety of their nanostructurized states [1-3]. Most commonly, this technology is applied to crystalline solids undergoing *MM-driven nanonization*, often accompanied by different phase transformations, including crystalline-to-amorphous transition (vitrification) due to large amount of mechanically-generated defects [3]. Nevertheless, the influence of MM on structurally disordered substances was relatively rare addressed.

Recently, numerous experiments probing vitrification dynamics in the nanostructurized glasses clearly demonstrates surface effects, revealed as negative deviations from bulk glass-transition temperature T_g (that is the T_g depression [4-7]) and *accelerated physical ageing* (see, e.g., ref. [8] and literature therein). This phenomenon was ascribed to liquid-like layer at the glass surface, which diverges as T_g is approached from below [4,5], while more microscopic picture of responsible transformations remains rather unclear.

In this work, we report first experimental results concerning MM effect on the intermediate-range structure of Se-rich glassy g-As_xSe_{100-x}, taken from domain of their pronounced network glass-forming ability [9-11], including boundary compositions of stoichiometric g-As₂Se₃ (i.e. g-As₄₀Se₆₀) and g-As₅Se₉₅.

Experimental

The studied alloys were prepared using coarse-grained pieces of bulk g-As_xSe_{100-x} (x=5, 10, 15, 17.5, 20, 22.5, 25, 29, 33, 35, 37, 40) preliminary synthesized from high-purity elemental precursors (As and Se of 5N purity acquired in Sigma Aldrich, USA) as described elsewhere [9-12]. The synthesized alloys were completely amorphous, as it follows from their X-ray powder diffraction (XRPD) patterns showing only broad diffuse halos proper to glassy substances, conch-like fracture of fresh-ingot cut sections and far IR transparency [9]. The plane-parallel plates (1.0-1.5 mm in a thickness) cut from thermally-annealed ingots (annealed at T_a temperature of 15-20°C below glass transition point T_g) were used as reference samples for input characterization. The densities ρ (± 0.005 g·cm⁻³) measured at room temperature by the Archimedes displacement technique in ethanol using the Mettler Toledo analytical balances, and mid-onset glass transition temperatures T_g (± 3 °C) determined from DSC scans performed under 10 K/min heating rate using TA Instrument Q20 calorimeter (Table 1), testify in favor of full adequacy of synthesized glasses with known counterparts from As-Se system [9-11].

The MM was performed in a dry mode using Pulverisette 6 mill (operated at 500 min⁻¹ rotational speed and protective argon atmosphere) for 20 min in 250 mL tungsten carbide chamber (loaded with 50 tungsten carbide balls each having 10 mm in a diameter), using ~3 g of coarse-grained glass of each composition preliminary sieved under 200 μ m. The high-energy MM in these conditions

does not change principally the amorphous state of the milled substances, as it follows from diffuse halos observed in their XRPD profiles. The particle sizes in the powders were detected by photon cross-correlation spectroscopy with Nanophox particle size analyzer (Sympatec) [13,14]. For each MM-affected sample, the typical single modal distribution was detected with x50 close to ~180 nm (meaning that 50 % of particles were smaller than 180 nm) and x99 close to ~270 nm (meaning that 99 % of particles were smaller than 270 nm), as it exemplified in Fig. 1 for milled g-As₄₀Se₆₀.

The identity of the milled phase was clarified by the XRPD analysis applied to the first sharp diffraction peak (FSDP), which is believed to be a signature of specific structural entities in glassy substances forming a so-called intermediate-range ordering over scale of a few tens of Å [15,16]. The XRPD data were collected in transmission mode on a STOE STADI P diffractometer [17] with linear position-sensitive detector (CuK α ₁-radiation, curved Ge (111) monochromator on primary beam, 2 θ / ω -scan). The raw results were corrected for empty instrument background, X-ray polarization, sample absorption, multiple and Compton scattering, Laue diffuse scattering and weighting correction, to obtain the total scattering structure function $S(Q)$, and its expression as the reduced scattering structure function, $F(Q) = Q[S(Q)-1]$, where Q is the magnitude of the scattering vector [18]. The X-ray structure factors $F(Q)$ were obtained using the PDFgetX2 software package [19], the accuracy of $S(Q)$ calculation according to standard deviations in output-files being ± 0.5 %.

Preliminary data processing was performed with STOE WinXPOW [17] and PowderCell [20] program packages, using information on crystal structures of arsenic selenides taken from known databases [21,22], in part, the JCPDS card No. 65-2365 for monoclinic As₂Se₃ and card No. 73-0465 for trigonal Se. The processing of the experimental XRPD profiles was performed using these programs, following normalization procedure taken in respect to the intensity of maximum peak. Then, the obtained data were used for next profile fitting exploring the WinPLOTR program [23]. Under used fitting protocol, we can compare correctly effects of MM on the halos-structured XRPD patterns of compositionally different g-As-Se samples, parameterized in *peak angular position* 2 θ and *full width at half maximum* (FWHM) defined within ± 0.05 °2 θ accuracy. The corresponding values of *scattering vector* Q and *width* ΔQ in a reciprocal space were calculated as:

$$Q = (4\pi/\lambda) \cdot \sin\theta, \quad (1)$$

$$\Delta Q = (4\pi/\lambda) \cdot \sin(\text{FWHM}/2). \quad (2)$$

The *characteristic distance* R (viz. the spacing of “quasi-periodicity” responsible for the FSDP, accepted this peak as a signature of remnants of crystallographic inter-planar periodicity) and *correlation length* L over which this “quasi-periodicity” is maintained were calculated as [24-33]:

$$R = 2\pi/Q, \quad (3)$$

$$L = 2\pi/\Delta Q. \quad (4)$$

We also explore the concept of diffuse halos in the XRPD patterns of amorphous substances arising from coordination spheres, i.e. groups of closest inter-atomic distances like in randomly-packed multiparticle systems [34-36], when scattering is governed by the Ehrenfest equation [37]:

$$2d_s \cdot \sin\theta = 1.23 \cdot \lambda, \quad (5)$$

where d_s is an average *inter-atomic distance* in a structure (i.e. distance between scattering centers defined as radius of corresponding coordination sphere).

Results and discussion

For a long time during last decades, the compositional variations in the FSDP-related XRPD patterns in binary g-As-Se have been in a sphere of tight interests, since these disordered substances are archetypal representatives for whole class of covalent-network glass formers [9-11]. Deviations in the FSDP position, intensity and width were subjected to scrupulous and systematic research in [31-33], showing perfect correlation with changing in g-As-Se composition.

The experimental XRPD patterns for both unmilled and milled g-As_xSe_{100-x} demonstrate broad diffuse peaks (“amorphous” halos) proper to g-As-Se/S [25-28]) revealed in a vicinity of ~15-22, ~28-32 and ~50-60 °2θ. In a reciprocal space, these halos can be scaled in respect to $Q \cdot d_s$ parameter (where d_s denotes an averaged inter-atomic distance in glass network) positioned at ~2-3, ~4.6-4.9, ~7.7-8.9 [26-29]. According to the Fourier-transform analysis [30], in a case of network-forming glassy materials, each of these features corresponds to a real-space ordering with characteristic distance R (“quasi-periodicity”) and correlation length L defined respectively by eqs. (1) and (2). For nearest inter-atomic distances of $d_s \cong 2.2\text{-}2.6 \text{ \AA}$ typical for glassy arsenic chalcogenides (e.g., $d_s \cong 2.43 \text{ \AA}$ for g-As₂Se₃ [9-11]), the first of these halos, associated with length scales commensurable with *intermediate-range ordering of glass-forming structural motifs*, is reproduced in the structure factor as the FSDP positioned at $Q \cong \sim 1\text{-}1.5 \text{ \AA}^{-1}$. Under the same inter-atomic distances d_s , the halo at ~28-32 °2θ (near $Q \sim 1.8\text{-}2.2 \text{ \AA}^{-1}$) referred to as principal diffraction peak (PDP) [29] is ascribed to *size of local network-forming motifs*, which are deterministic for so-called *extended-range ordering* in a glass [15]. Correspondingly, the third peak at ~50-60 °2θ associated with *nearest-neighbor separations* in a glass [29] corresponds to scattering vectors $Q \sim 3.3\text{-}4.0 \text{ \AA}^{-1}$.

The XRPD profiles collected for some unmilled and milled g-As_xSe_{100-x} specimens as compared with calculated ones are shown in Fig. 2 and 3, respectively. The same features are also revealed in low- Q part of the reduced X-ray structure factor $F(Q) = Q(S(Q)-1)$ depicted in Fig. 4. The FSDP parameters calculated for all these samples are gathered in Table 2.

It is seen that with increase in Se content (decrease in x parameter), the FSDP position in g-As_xSe_{100-x} shifts to higher scattering vectors Q , these values for unmilled samples being in an excellent agreement with data of other authors [31-33]. Simultaneously, under decreased x parameter, the FSDP is affected to substantial broadening in the width ΔQ . In the structure factor

$F(Q) = Q(S(Q)-1)$ determination, the FSDP parameters of unmilled g-As₂Se₃ reach $Q=1.28 \text{ \AA}^{-1}$ and $\Delta Q=0.43 \text{ \AA}^{-1}$ (Fig. 4), while the PDP observed at $2.23 \text{ \AA}^{-1}$ is wider in a width ($0.54 \text{ \AA}^{-1}$). With increase in Se content beyond As₂Se₃ composition ($x=40$), the FSDP becomes merely reduced in its magnitude and broaden in a width, being shifted towards higher scattering vectors Q (so demonstrating high- Q shift seen from Fig. 4). Under this trend, the PDP remotes in an opposite direction demonstrating very strong low- Q shift. Thus, approaching g-Se in g-As-Se, the intermediate-range ordering determined by the FSDP is depressed being covered by extended-range ordering due to low- Q shifted PDP at $\sim 26-28^\circ 2\theta$ (corresponding to $Q \sim 1.6-1.7 \text{ \AA}^{-1}$).

The high-energy MM does not change principally an overall character of these XRPD patterns. Thus, in the milled g-As_xSe_{100-x} ($5 \leq x \leq 40$), the FSDP position Q and, respectively, the spacing of the FSDP-responsible “quasi-periodicity” R remains nearly the same as in unmilled samples (Table 2). In contrast, the FSDP width ΔQ is slightly enhanced under MM and, respectively, the correlation length L is more reduced, this effect being observed for milled g-As_xSe_{100-x} samples with $20 \leq x < 40$. The relative changes in the correlation length $\Delta L/L_0$ calculated in respect to unmilled samples reach 5-6 %, while changes in the periodicity $\Delta R/R_0$ remains within measuring error-bar (no more 0.8 %), except close to stoichiometric glass compositions with $40 \leq x < 35$ (see Table 2). These effects are not accompanied by changes in the PDP (neither in peak position Q nor in width ΔQ), speaking in a favor of MM-driven modification of intermediate-range ordering alone.

Despite controversies concerning the FSDP origin in covalent-bonded glass formers, this peak is generally accepted as a manifestation of intermediate-range order in a glass structure [15,16]. Recently the Gaskell’s concept on crystalline-like remnants in melt-quenched (MQ) glasses [38] modified with Wright’s justification for the FSDP as arising from a periodicity in the distribution of some “pseudo-planes” for the Bragg diffraction separating succession of randomly-packed network cages [39], was applied to interpret crystalline-to-amorphous transition in arsenic chalcogenides affected to high-energy MM [40,41]. In respect to this concept, the flattened cage structure of covalent-bonded network glasses produces inner equivalent planes at opposite sides of these cages forming a necessary contribution to the reciprocal space Fourier component generating the FSDP [39]. Therefore, the FSDP is ascribed to variations in the underlying cage structure of glassy network defined by interlinked polyhedrons (glass-forming building blocks) producing multiple cycle-type entities, which keep some elements of inter-planar “ordering” proper to crystalline counterparts of these glasses of close chemical compositions.

Within this concept [38,39] applied to g-As_xSe_{100-x} ($5 \leq x \leq 40$), the FSDP can be attributed to covalent-bonded network structure built of trigonal AsSe_{3/2} pyramids interlinked by Se-chains, i.e. inter-planar “ordering” character for crystalline As₂Se₃ (with specific 12-membered corrugated rings within *ac* plane [9,42-44]), disturbed by incorporated (-Se-Se-)_n chains of different length n (dependently on a glass composition) [45-54]. With Se additions to stoichiometric g-As₂Se₃, the

FSDP-responsible inter-planar ordering does not change essentially. The higher content of homonuclear Se-Se bonds in a glassy network, which are shorter than other covalent chemical bonds in g-As-Se ($l_{\text{Se-Se}} \approx 2.32 \text{ \AA}$, $l_{\text{As-Se}} \approx 2.43 \text{ \AA}$, $l_{\text{As-As}} \approx 2.53 \text{ \AA}$ [9-11]), the shorter average inter-atomic distance d_s , and, respectively, the smaller “quasi-periodicity” R , while the correlation length L decreases only slightly (see Table 2). These changes are accompanied by dropping in the FSDP intensity, this effect being accompanied by evident increase in the L with Se addition when going over a barrier of ~80 at. % Se. The boundary composition (i.e. g-As₂₀Se₈₀) corresponding to the eutectic in the phase diagram of As-Se system [9,11,52,53] can be specified as a threshold between network of AsSe_{3/2} pyramids linked by (-Se-Se-)_n chains with an essential role of cation-cation correlations, and network of Se-rich entities in preferential *trans*- (Se-chains) and/or *cis*-atomic configurations (Se-rings) [39,53,54]. In the latter, the cation-cation correlations responsible for the FSDP [31] became inessential diminishing this peak with further Se content.

Under high-energy MM, the existing thermodynamically stabilized balance in network-forming entities is essentially disturbed, providing an evidence on their defective states with unfavorable potential energies. From inspection of Table 2, it seems that MM does not influence the FSDP-responsible correlations in g-As_xSe_{100-x} close to g-Se (5<x<20), where Se-rich entities are obviously dominated in the structural network. At the same time, slight increase in the FSDP width ΔQ for milled g-As_xSe_{100-x} with 20≤x≤40 can be ascribed to reduction in the correlation length L due to different structural defects generated under MM, which disturb the FSDP-responsible inter-planar “ordering” due to built-in attrition stress. This compositional domain in binary g-As-Se is known to be full of different structural-network instabilities, such as local decomposition on As- and Se-rich fragments or global separation on As₂Se₃-rich and Se-rich phases [54]. Such anomalies activated by ball MM occur fragmentation effect on the correlation length L of the FSDP-responsible “quasi-periodicity”.

In general, from the point of thermodynamic enthalpic diagram for glass-forming liquids [8,9], the MQ glassy substance is closer to the equilibrium state than that subjected to high-energy MM. This conclusion essentially depends on the cooling rate of melt liquid (at slow cooling rate, the near-equilibrium glasses dominate, while far-from-equilibrium glasses are preferred at rapid cooling) [9]. In such consideration, the milled substance is undoubtedly closer to out-of-equilibrium state of fine-grained powder. It should be expected that under increased energy transferred to solid system under high-energy MM (e.g., due to increased rotational speed or more prolonged milling), the most out-of-equilibrium state will be achieved because of large number of structural defects appeared at such conditions. Thermodynamic characteristics of amorphous solids derived from different states (melt, super-cooled liquid, or crystal) due to applied amorphization technique is expected to deviate as for extra-rapidly MQ glass affected to prolonged physical ageing, this effect being essentially dependent on glass composition [8,9].

More straightforward interpretation of the observed compositional variations in the XRPD patterns of g-As-Se can be presented accepting their diffuse halos as additionally disturbed by pair *inter-atomic correlations*, i.e. superimposed the Ehrenfest diffraction halos originated from coordination spheres (see, e.g., ref. [35] and cited literature therein). In a strong meaning, such approach alone is confirmed only for randomly-packed multiparticulate substances [34-36], which are classified in this view as *ideal amorphous solids* obeying geometrical structural model composed of contacting hard spheres in a space positioned in a random way [36]. In application to covalent-bonded substances (like chalcogenide glasses) possessing atomic-network structure comprising short- and intermediate-range ordering, this approach is not strictly applicable [24,36]. The governing role of the XRPD signatures attributed to “quasi-crystalline” inter-planar correlations in such a case can be credibly documented by close similarity between diffuse halos and strongest reflexes of crystalline homologs of these glasses of close compositions [55,56]. Thus, Fig. 5 demonstrates the XRPD profiles for unmilled and milled g-As₄₀Se₆₀ in comparison with theoretical Bragg diffraction reflexes for monoclinic As₂Se₃ and trigonal Se [21,22]. As stated above, the XRPD patterns of such substances contain a few spatially-separated diffuse halos at ~50-60, ~28-32 and ~15-22 °2θ, where third one is referred to as the FSDP [25-33]. With the Ehrenfest eq. (5), this peak-halo is ascribed to the X-ray diffraction from averaged *inter-atomic* distances d_s , changing smoothly from 6.05 Å in g-As₄₀Se₆₀ to 5.42 in g-As₅Se₉₅ (Table 2). In g-As-Se, these d_s correspond to character distances between cation-like atoms of some fragments belonging to different more or less separated atomic clusters (quasi-layers), forming *third-order nearest-neighbor* (As)---(As) pairs *correlations* [15,16,31-33]. At least two of these *inter-atomic* distances prevail over others in glassy chalcogenides [9-11,57,58]. Thus, in the atomic arrangement of both glassy and crystalline As₂Se₃, the dominated d_s approaching ~5.8 and ~6.9 Å terminated by deep depopulation regions can be well detected (see Fig. 3 in ref. [57]). In this glass, the lower d_s is expected for right-sided wing of the FSDP (observed at higher diffraction angles 2θ), while the longer distances are proper to left-sided part of this peak (observed at lower diffraction angles 2θ).

Therefore, we believe the FSDP in g-As_xSe_{100-x} (5≤x≤40) monitored at scattering vectors $Q \sim 1.28\text{--}1.42 \text{ \AA}^{-1}$ can be attributed to commensurable contributions from (i) *inter-planar* correlations due to “quasi-crystalline” remnants of close compositions (monoclinic As₂Se₃ and trigonal Se) with character Bragg diffraction lengths $R = 4.92\text{--}4.43 \text{ \AA}$, and (ii) *inter-atomic* correlations due to third-order nearest-neighbor (As)---(As) pairs with character $d_s = 6.05\text{--}5.45 \text{ \AA}$ (the digits are given in a sequence of increasing Se content, Table 2).

This multi-level structure-forming specificity is assumed to be a reason for anomalous behavior of the FSDP under compositional variations, applied pressure, temperature or other influences. Thus, e.g., if the *inter-planar* distance R is decreased under some factors, such as applied pressure, thus resulting in high- Q shift in the FSDP position, the accompanied changes in (As)---(As) *inter-*

atomic distances d_s are inadequate because of orientation displacements of neighboring structural fragments (molecular clusters or quasi-layers). Some *inter-atomic* distances d_s occur to be increased at a cost of decreased others, both contributing to the same coordination sphere producing the XRPD halo near $Q \sim 1 \text{ \AA}^{-1}$ (the FSDP). Under *acentric* displacements of constituting quasi-layers or molecules, this densification trend may result in somewhat decreased shorter distances d_s , but increased longer ones. Correspondingly, the increased inter-atomic distances remote from the FSDP-related contributions, depressing the FSDP intensity and shifting it towards shorter d_s , these changes being in excellent agreement with known experimental observations showing FSDP shifting to higher Q accompanied by broadening and decaying under densification [16,59,60].

So we can speculate that under MM some *inter-atomic* distances d_s contributing to the FSDP are destroyed owing to created defects, giving rise to others. Essential reduction of such inter-atomic (As)---(As) correlations in initial (unmilled) state as resulted from atomic pairs distributions derived by Renninger and Averbach [57], make $\text{g-As}_x\text{Se}_{100-x}$ with $x < 20$ stable against MM (no detectable changes in the FSDP position Q and width ΔQ , Table 2). Presumably, main compositional trend in the FSDP position showing strong tendency to higher 2θ with Se content is governed by broadened *inter-planar* Bragg reflexes from crystalline phases, these being monoclinic As_2Se_3 [43,44] with intensive (91.9 %) line from *inter-layer* (020) planes (at $\sim 17.9^\circ 2\theta$, $d = 4.95185 \text{ \AA}$) and trigonal Se [61] with more than twice weaker (50 % in intensity) line from (100) planes at $\sim 23.5^\circ 2\theta$ corresponding to $3.78124 \text{ \AA}$ distance (Fig. 5).

As to the PDP positioned in $\text{g-As}_2\text{Se}_3$ at $Q \sim 2.23 \text{ \AA}^{-1}$ (which is equivalent to $\sim 31.7^\circ 2\theta$) [29,36]), the responsible *inter-atomic* correlations d_s for this peak calculated from the Ehrenfest eq. (5) reach for g-As-Se $3.6\text{--}4.0 \text{ \AA}$, the values which can be ascribed to nearest-neighbor distances related to second-order (As)---(Se) and (Se)---(Se) atomic pairs. Such attributes can be found, in part, in the crystallographic projection of crystalline As_2Se_3 within centrosymmetrically equivalent composite polyhedrons around two As sites as defined by Stergiou and Rentzeperis [43]. That is why angular positions of both *inter-planar* “quasi-crystalline” R and *inter-atomic* d_s correlations contributing to this peak coincide merely. As to compositional trends followed from atomic radial distributions derived by Renninger and Averbach [56], the *inter-atomic* correlations at $d_s \sim 3.7 \text{ \AA}$ are full invariant with Se content in g-As-Se . Therefore, the compositional changes in this region are governed by Bragg diffraction of “quasi-crystalline” *inter-planar* correlations, showing strong low- Q shift with Se content due to preference of broad crystallographic reflexes of trigonal Se (Fig. 5), that is 100 % in intensity (101) planes ($\sim 30.0^\circ 2\theta$, $d = 3.00565 \text{ \AA}$) and 50 % in intensity (100) planes ($\sim 23.5^\circ 2\theta$, $d = 3.78124 \text{ \AA}$) [61]. Noteworthy, the PDP-related *inter-atomic* distances d_s correlate well with mean inter-atomic spacing $l_s = (6 \cdot \mu / \pi \cdot \rho \cdot N_A)^{1/3}$ in Table 1 (μ – molecular mass of glass, N_A – the Avogadro’s number) derived from macroscopic densities ρ of g-As-Se .

Finally, the diffuse peak in the XRPD patterns at $\sim 50-60^\circ 2\theta$ (not shown in Fig. 2 and 3), reproducible via the Ehrenfest eq. (5) as proper to mean inter-atomic distances of $d_s=2.0-2.1 \text{ \AA}$ (which is less than character first-order nearest-neighbor bond lengths in binary g-As-Se), is most controversial in this interpretation. It should be emphasized that strict one-to-one correspondence within the Ehrenfest eq. (5) is appropriate only for amorphous substances obeying structural models built of hard contacting spheres like those proper to metallic glasses [24,36]. In semiconductor network covalent-bonded glasses, where these peaks originates from competition between rapidly-decreasing form-factor for separate structural units (building blocks like trigonal $\text{AsSe}_{3/2}$ pyramids, $\text{GeSe}_{4/2}$ tetrahedrons, etc.) and raising structure factor associated with their spatial packaging [62], this correspondence is not strictly satisfied due to directionality of covalent bonds preventing glass structure from close nearest-neighbor packing in the shortest coordination sphere. Respectively, the Ehrenfest relation (5) in its original form cannot be further applied as the Master equation covering realistic shortest inter-atomic distances d_s in covalent-bonded systems without additional correction. At the basis of data for g- As_2Se_3 gathered in Table 2, this correction can be simply enter with multiplying coefficient of ~ 1.14 , thus giving remarkable correspondence with peak position d_s attributed to As-Se bond length ($\sim 2.43 \text{ \AA}$). The governing compositional trend in this peak-halo in Se-rich g-As-Se also corresponds to changes in mean inter-atomic spacing l_s showing smooth increase towards Se-rich compositions (see Table 1).

It worth mentioning interpretation of the FSDP-related dependences in g-As-Se in terms of XRPD patterns originated from remnants of “quasi-crystalline” *inter-planar* correlations supplemented by diffuse halos originated from strongest *inter-atomic* correlations in a glass network, has an obvious advantage over models treated these patterns as arising from “quasi-periodicity” of crystallographic planes only. Indeed, within this approach, we explain appearance of additional diffuse halos at smaller diffraction angles of $\sim 5-7^\circ 2\theta$ (Fig. 2, 3 and 5) in the region without any close “quasi-crystalline” *inter-planar* reflexes (so-called *pre-FSDP* [63-67]) as corresponding to extended *super-structural units*, which reveal more prolonged *inter-atomic* correlations reaching $d_s \sim 15-20 \text{ \AA}$. An original interpretation can be also provided for high-angular shoulder in the right-sided FSDP wing or so-called *post-FSDP* [63] observed at $\sim 20-22^\circ 2\theta$ (see Fig. 2, 3 and 5) or $Q \sim 1.5 \text{ \AA}^{-1}$ (see Fig. 4). Such feature causing an essential asymmetry in the FSDP shape (as was pointed out by Ke. Tanaka for photo-expanded chalcogenide films [68]), was observed often in the XRPD patterns of many bulk glassy alloys (especially those doped with metals), such as g- As_2S_3 [28,69] and near-stoichiometric g- $\text{As}_{38}\text{S}_{62}$ and g- $\text{As}_{42}\text{S}_{58}$ [69], As_2S_3 -In/I/GaSb [64,66], Ge-Sb-S [65], Ge-As-Se [67], GeSe_2 - Ga_2Se_3 [70,71], As_2Se_3 -Ga [72], and even $\text{As}_{45}\text{S}_{55}$ amorphized by high-energy MM [73]. To the best of our knowledge, this specificity has been remained without explanation, giving a ground for supposition on possible doublet-type constitution of the FSDP in chalcogenide glasses. Indeed, this shoulder corresponding to *inter-*

atomic distances approaching $d_s=5.1-5.3 \text{ \AA}$ (irrespective to glass composition), can be ascribed to the Ehrenfest diffraction from some remnants of “quasi-crystalline” correlations, which also contribute to the FSDP through more intensive Bragg reflection.

From a standpoint of the XRPD in chalcogenide glasses originated from coordination spheres, the MM-induced invariance in the FSDP positions Q for $\text{g-As}_x\text{Se}_{100-x}$ ($5 \leq x \leq 40$) means unchangeable behavior of *inter-atomic* distances d_s contributing to the FSDP-responsible coordination sphere (the maximal changes $\Delta d_s/d_{s0}$ after milling do not exceed the reliable error-bar of $\pm 1.0 \%$, see Table 2). In more Se-rich glasses with $5 \leq x \leq 20$, this effect is concomitant with nearly constant FSDP width ΔQ (or peak FWHM) for unmilled and milled samples, this effect being ascribed to unchanged distribution of these *inter-atomic* distances d_s . In contrast, the glasses with $20 \leq x \leq 40$ demonstrate slight increase in the FSDP width ΔQ after high-energy MM owing to broadening in the distribution of characteristic *inter-atomic* distances d_s contributing to the FSDP, thus testifying in a favor of more destructed glass structure in the milled state.

Conclusions

The FSDP-related correlations are studied in the XRPD patterns of Se-rich $\text{As}_x\text{Se}_{100-x}$ glasses ($5 \leq x \leq 40$), modified by high-energy mechanical ball milling in a dry mode with 500 min^{-1} rotational speed. The results are treated in terms of structural model assuming appearance of broad diffuse halos due to remnants of *inter-planar* “quasi-crystalline” correlations (in respect to the Gaskell-Wright’s concept on microcrystalline ordering in network glass-formers [38,39]), supplemented by halos originated from strongest *inter-atomic* correlations, in part, the nearest-neighbor correlations between cation-like atoms. It is shown that high-energy mechanical milling does not influence the FSDP position Q in a vicinity of glassy Se ($5 < x < 20$), but increase the FSDP width ΔQ (reduction in the correlation length L) for $\text{g-As}_x\text{Se}_{100-x}$ with $20 \leq x < 40$, the latter being caused by disturbed inter-planar arrangement due to generated structural defects. Alternatively, this effect is ascribed to broadening in the distribution of characteristic *inter-atomic* distances d_s contributing to the FSDP, thus testifying in a favor of more destructed glass structure in the milled state.

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Fig. 1. Typical particle size distribution in g-As₄₀Se₆₀ affected to high-energy MM.

Fig. 2. Experimental (red points) and calculated (black solid line) XRPD profiles for unmilled g-As₅Se₉₅ (a), g-As₁₀Se₉₀ (b), g-As₂₀Se₈₀ (c), g-As₂₉Se₇₁ (d), g-As₃₅Se₆₅ (e), g-As₄₀Se₆₀ (f) showing the FSDP around 12-25 °2 θ (the difference curve is given at the bottom by blue solid line).

Fig. 3. Experimental (red points) and calculated (black solid line) XRPD profiles for milled g-As₅Se₉₅ (a), g-As₁₀Se₉₀ (b), g-As₂₀Se₈₀ (c), g-As₂₉Se₇₁ (d), g-As₃₅Se₆₅ (e), g-As₄₀Se₆₀ (f) showing the FSDP around 12-25 °2 θ (the difference is given at the bottom by blue solid line).

Fig. 4. Low- Q part of the reduced X-ray structure factor $F(Q) = Q(S(Q)-1)$ for milled g-As_xSe_{100-x} (the x parameter is denoted under the curve, which is offset along the y axis, for clarity). Slight shoulder at $Q \cong \sim 1.5 \text{ \AA}^{-1}$ producing the FSDP asymmetry is visible (see text for more details).

Fig. 5. Experimental XRPD profiles for unmilled (green curve) and milled (black curve) g-As₄₀Se₆₀ as compared with theoretical Bragg diffraction reflexes for monoclinic As₂Se₃ (red lines) and trigonal Se (blue lines). The most intense diffraction lines of these crystals are denoted, slight shoulder around ~20-22 °2 θ is detectable in both g-As₄₀Se₆₀ samples (see text for more details).

Table 1. Input characterization of the synthesized g-As_xSe_{100-x} alloys.

x	T_a	$\rho, \text{g}\cdot\text{cm}^{-3}$	$T_g, ^\circ\text{C}$	$l_s, \text{\AA}$
5	50 °C	4.314	65	3.87
10	60 °C	4.348	81	3.86
15	65 °C	4.385	92	3.84
17.5	70 °C	4.402	96	3.83
20	75 °C	4.420	102	3.83
22.5	80 °C	4.444	106	3.82
25	90 °C	4.468	112	3.81
29	115 °C	4.503	124	3.80
33	130 °C	4.546	138	3.78
35	140 °C	4.567	148	3.78
37	150 °C	4.593	163	3.77
40	160 °C	4.605	184	3.77

Table 2. The FSDP parameterization in unmilled and milled g-As_xSe_{100-x}.

Sample x, state	2θ ° 2θ	$FWHM$ ° 2θ	Q Å ⁻¹	ΔQ Å ⁻¹	R Å	$\Delta R/R_0$ %	L Å	$\Delta L/L_0$ %	d_s Å	$\Delta d_s/d_{s0}$ %
x=40; unmilled	18.014(13)	6.02(4)	1.28	0.43	4.92	-	14.67	-	6.05	-
x=40; milled	17.862(11)	6.02(3)	1.27	0.43	4.96	+0.8	14.65	-0.1	6.10	0.8
x=37; unmilled	18.251(13)	6.20(4)	1.29	0.44	4.86	-	14.26	-	5.97	-
x=37; milled	18.133(13)	6.33(4)	1.28	0.45	4.89	+0.6	13.96	-2.1	6.01	0.7
x=35; unmilled	18.355(13)	6.44(4)	1.30	0.46	4.83	-	13.72	-	5.94	-
x=35; milled	18.231(14)	6.60(4)	1.29	0.47	4.86	+0.6	13.38	-2.5	5.98	0.7
x=33; unmilled	18.423(14)	6.25(4)	1.31	0.44	4.81	-	14.14	-	5.92	-
x=33; milled	18.369(15)	6.70(5)	1.30	0.48	4.83	+0.4	13.18	-6.8	5.94	0.3
x=29; unmilled	18.697(14)	6.47(4)	1.32	0.46	4.74	-	13.65	-	5.83	-
x=29; milled	18.633(14)	6.81(4)	1.32	0.48	4.76	+0.4	12.97	-5.0	5.85	0.3
x=25; unmilled	18.977(17)	6.43(5)	1.34	0.46	4.67	-	13.73	-	5.75	-
x=25; milled	18.917(16)	6.84(4)	1.34	0.49	4.69	+0.4	12.91	-6.0	5.77	0.3
x=22.5; unmilled	19.110(22)	6.64(6)	1.35	0.47	4.64	-	13.30	-	5.71	-
x=22.5; milled	19.092(19)	7.04(5)	1.35	0.50	4.64	0	12.54	-5.7	5.71	0
x=20; unmilled	19.323(21)	6.80(9)	1.37	0.48	4.59	-	13.00	-	5.65	-
x=20; milled	19.236(27)	6.58(7)	1.36	0.47	4.61	+0.4	13.43	+3.3	5.67	0.4
x=17.5; unmilled	19.490(21)	6.31(5)	1.38	0.45	4.55	-	13.99	-	5.60	-
x=17.5; milled	19.532(22)	6.26(5)	1.38	0.45	4.54	-0.2	14.10	+0.8	5.58	-0.4
x=15; unmilled	19.621(22)	6.03(5)	1.39	0.43	4.52	-	14.64	-	5.56	-
x=15; milled	19.597(24)	6.00(5)	1.39	0.43	4.53	+0.2	14.71	+0.5	5.57	0.2
x=10; unmilled	19.962(28)	5.54(6)	1.41	0.39	4.44	-	15.94	-	5.46	-
x=10; milled	19.901(26)	5.58(6)	1.41	0.40	4.46	+0.5	15.83	-0.7	5.48	0.4
x=5; unmilled	20.011(5)	4.51(13)	1.42	0.32	4.43	-	19.56	-	5.45	-
x=5; milled	20.101(27)	4.57(8)	1.42	0.33	4.41	-0.5	19.31	-1.3	5.42	-0.5

Fig. 1. Typical particle size distribution in g-As₄₀Se₆₀ affected to high-energy MM.

Fig. 2. Experimental (red points) and calculated (black solid line) XRPD profiles for unmilled $\text{g-As}_5\text{Se}_{95}$ (a), $\text{g-As}_{10}\text{Se}_{90}$ (b), $\text{g-As}_{20}\text{Se}_{80}$ (c), $\text{g-As}_{29}\text{Se}_{71}$ (d), $\text{g-As}_{35}\text{Se}_{65}$ (e), $\text{g-As}_{40}\text{Se}_{60}$ (f) showing the FSDP around $12-25^\circ 2\theta$ (the difference curve is given at the bottom by blue solid line).

Fig. 3. Experimental (red points) and calculated (black solid line) XRPD profiles for milled g-As₅Se₉₅ (a), g-As₁₀Se₉₀ (b), g-As₂₀Se₈₀ (c), g-As₂₉Se₇₁ (d), g-As₃₅Se₆₅ (e), g-As₄₀Se₆₀ (f) showing the FSDP around 12-25 °2 θ (the difference is given at the bottom by blue solid line).

Fig. 4. Low- Q part of the reduced X-ray structure factor $F(Q) = Q(S(Q)-1)$ for milled $g\text{-As}_x\text{Se}_{100-x}$ (the x parameter is denoted under the curve, which is offset along the y axis, for clarity). Slight shoulder at $Q \cong \sim 1.5 \text{ \AA}^{-1}$ producing the FSDP asymmetry is visible (see text for more details).

Fig. 5. Experimental XRPD profiles for unmilled (green curve) and milled (black curve) g- $\text{As}_{40}\text{Se}_{60}$ as compared with theoretical Bragg diffraction reflexes for monoclinic As_2Se_3 (red lines) and trigonal Se (blue lines). The most intense diffraction lines of these crystals are denoted, slight shoulder around $\sim 20\text{--}21^\circ 2\theta$ is detectable in both g- $\text{As}_{40}\text{Se}_{60}$ samples (see text for more details).

Highlights

Intermediate-range ordering in $\text{As}_x\text{Se}_{100-x}$ glasses modified under high-energy milling

FSDP position and width are milling-invariant in Se-rich $\text{As}_x\text{Se}_{100-x}$ glasses ($x < 20$)

Increased FSDP width in glassy $\text{As}_x\text{Se}_{100-x}$ ($20 \leq x \leq 40$) due to milling-derived defects